

| | Type | Hits | Search Text | DBs |
|----|------|------|---|---|
| 24 | BRS | 734 | ((open opened opening) adj drain) with (MOSFET FET transistor gate) | USPAT |
| 25 | BRS | 579 | (((open opened opening) adj drain) not (((open opened opening) adj drain) with (MOSFET FET transistor gate))) and substrate | USPAT |
| 26 | IS&R | 3086 | (257/107,133,335-339,341-343,350).CCLS. | USPAT; USOCR |
| 27 | BRS | 3660 | (open opened opening) adj drain | US-PGPUB; EPO; JPO; DERWENT; IBM_TDB |
| 28 | BRS | 744 | ((open opened opening) adj drain) with (MOSFET FET transistor gate) | USPAT |
| 29 | BRS | 599 | (((open opened opening) adj drain) not (((open opened opening) adj drain) with (MOSFET FET transistor gate))) and substrate | USPAT |
| 30 | BRS | 3852 | (open opened opening) adj drain | US-PGPUB; EPO; JPO; DERWENT; IBM_TDB |
| 31 | IS&R | 1140 | (438/152,155,156,309,311).CCLS. | USPAT |
| 32 | IS&R | 363 | (438/152,155,156,309,311).CCLS. | US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB |
| 33 | BRS | 147 | ((257/107,133,335-339,341-343,350).CCLS.) and ((electric adj static adj discharge) ESD (static adj charge)) | USPAT |
| 34 | BRS | 33 | ((257/107,133,335-339,341-343,350).CCLS.) and ((electric adj static adj discharge) ESD (static adj charge)) | US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB |
| 35 | BRS | 40 | ((438/152,155,156,309,311).CCLS.) and ((electric adj static adj discharge) ESD (static adj charge)) | USPAT |
| 36 | BRS | 18 | ((438/152,155,156,309,311).CCLS.) and ((electric adj static adj discharge) ESD (static adj charge)) | US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB |
| 37 | IS&R | 3210 | (257/107,133,335-339,341-343,350).CCLS. | USPAT; USOCR |
| 38 | IS&R | 1709 | (257/107,133,335-339,341-343,350).CCLS. | US-PGPUB; EPO; JPO; DERWENT; IBM_TDB |